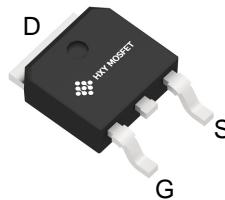




Description

The HXY10N65D can be used in various power switching circuit for system miniaturization and higher efficiency. The package form is TO-252-2L, which accords with the RoHS standard.



TO-252-2L

General Features

$V_{DS} = 650V$ $I_D = 10A$

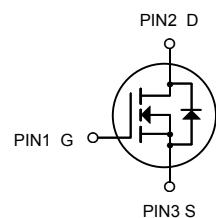
$R_{DS(ON)} < 1.0 \Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HXY10N65D	TO-252-2L	10N65D XXXX	2500

Absolute Maximum Ratings (T_c=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage	± 30	V
$I_D@T_c=25^\circ C$	Continuous Drain Current, V_{GS} @ 10V	10	A
$I_D@T_c=100^\circ C$	Continuous Drain Current, V_{GS} @ 10V	5.8	A
I_{DM}	Pulsed Drain Current	40	A
$P_D@T_c=25^\circ C$	Total Power Dissipation	39	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C
$R_{\theta JA}$	Thermal Resistance Junction-ambient	43.3	°C/W
$R_{\theta JC}$	Thermal Resistance Junction-Case	3.8	°C/W

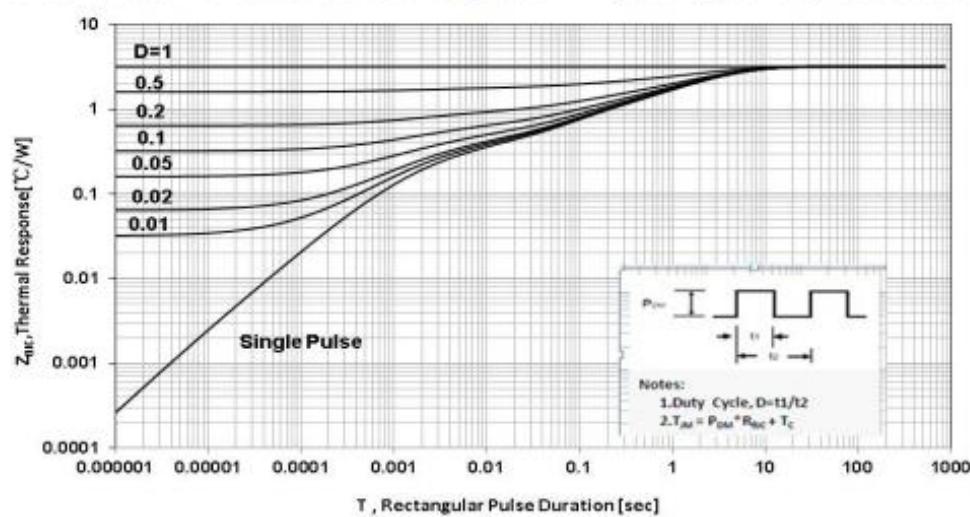
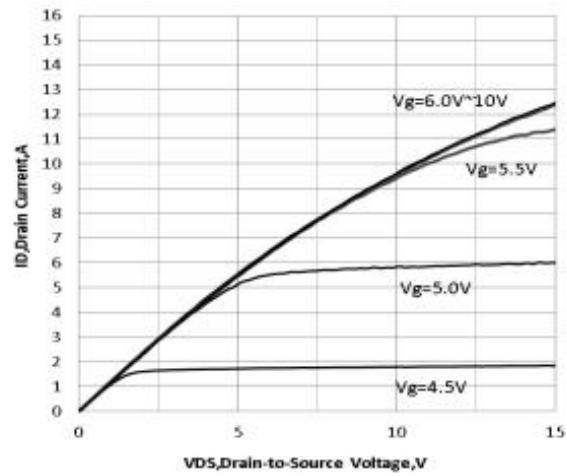
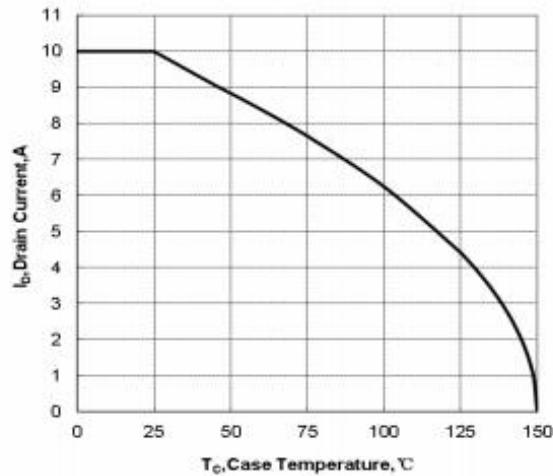
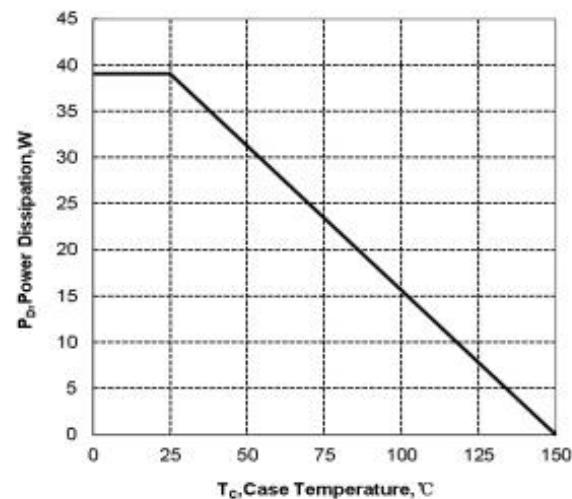
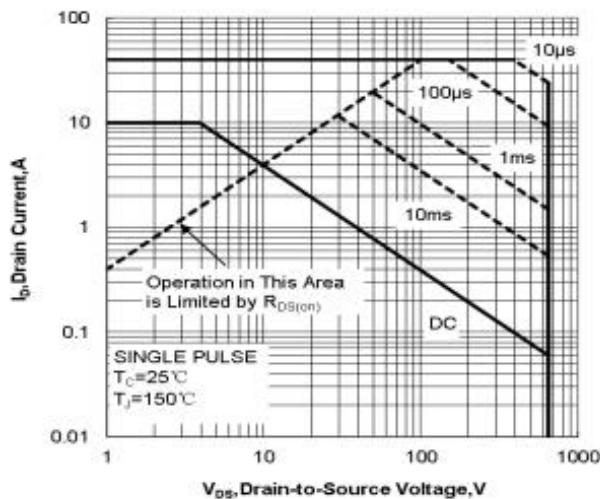


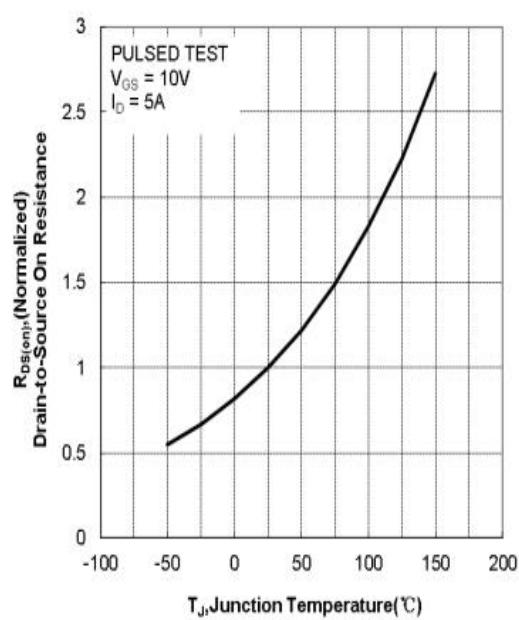
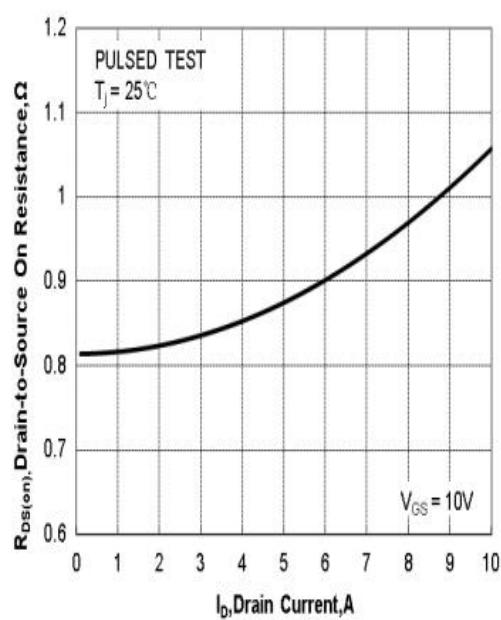
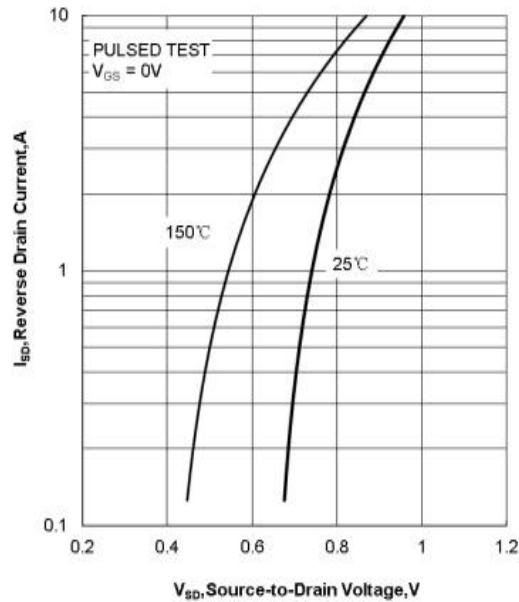
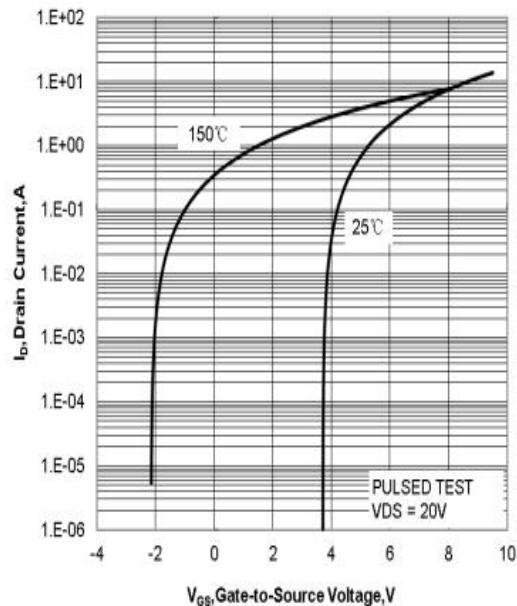
Electrical Characteristics (T_J= 25°C,unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	650	---	---	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} =0V, V _{DS} =650V	---	---	1	μA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±30V, V _{DS} =0A	---	---	±100	nA
V _{GS(th)}	GATE-Source Threshold Voltage	V _{GS} =V _{DS} , I _D =250μA	2	---	4	V
R _{DS(ON)}	Drain-Source On Resistance	V _{GS} =10V, I _D =3.5A	---	0.85	1.0	Ω
g _{FS}	Forward Transconductance	V _{GS} =40V, I _D =3.5A ⁴	2.5	---	---	S
C _{iss}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	---	1570	---	pF
C _{oss}	Output Capacitance		---	166	---	
C _{rss}	Reverse Transfer Capacitance		---	18	---	
t _{d(on)}	Turn-On Delay Time	V _{DD} =325V, I _D =7A, R _{GEN} =2.5Ω ^{4,5}	---	23	---	ns
t _r	Rise Time		---	69	---	ns
t _{d(off)}	Turn-Off Delay Time		---	144	---	ns
t _f	Fall Time		---	77	---	ns
Q _g	Total Gate Charge	V _{GS} =10V, V _{DS} =520V, I _D =7A ^{4,5}	---	44	---	nC
Q _{gs}	Gate-Source Charge		---	6.7	---	nC
Q _{gd}	Gate-Drain "Miller" Charge		---	18.5	---	nC
V _{SD}	Source-Drain Diode Forward Voltage	V _{GS} =0V, I _S =10A	---	---	1.4	V
I _s	Continuous Source Current	---	---	---	7	A
I _{sm}	Pulsed Source Current		---	--	28	Ns
trr	Reverse Recovery Time	V _{GS} = 0 V, I _S = 7 A, 4 dI _F / dt = 100 A/μs	---	389	---	ns
Qrr	Reverse Recovery Charge		---	2.04	---	μ C



Typical Characteristics





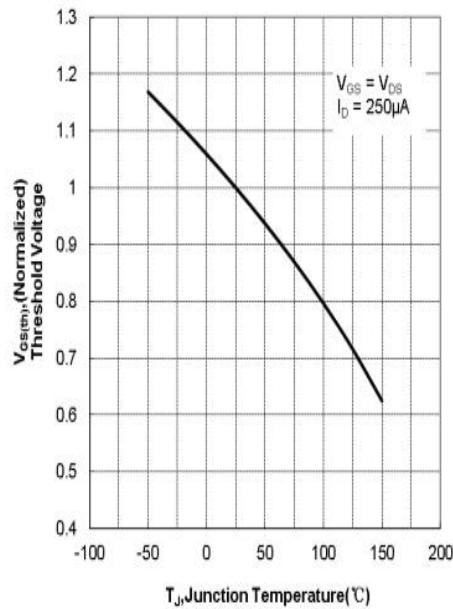


Figure.10 Typical Threshold Voltage vs Junction Temperature

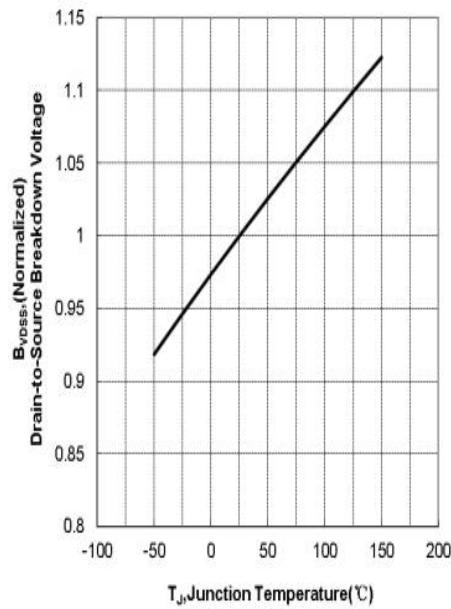


Figure 11 Typical Breakdown Voltage vs Junction Temperature

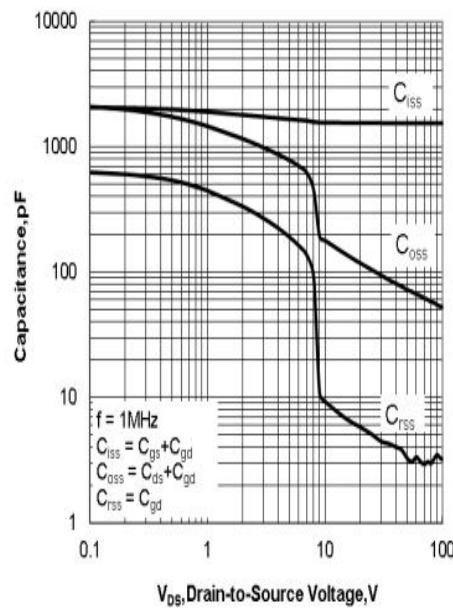


Figure.12 Typical Capacitance vs Drain to Source Voltage

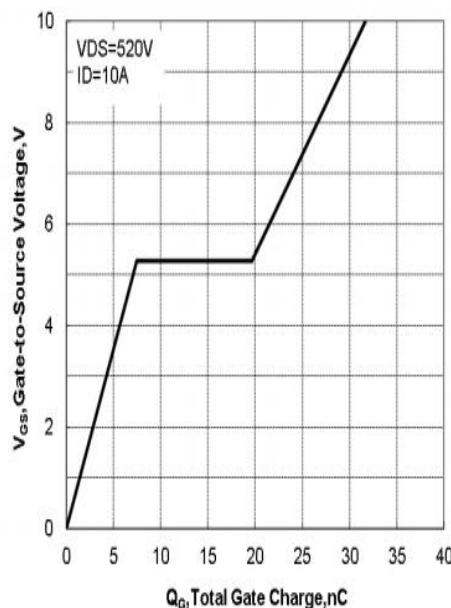
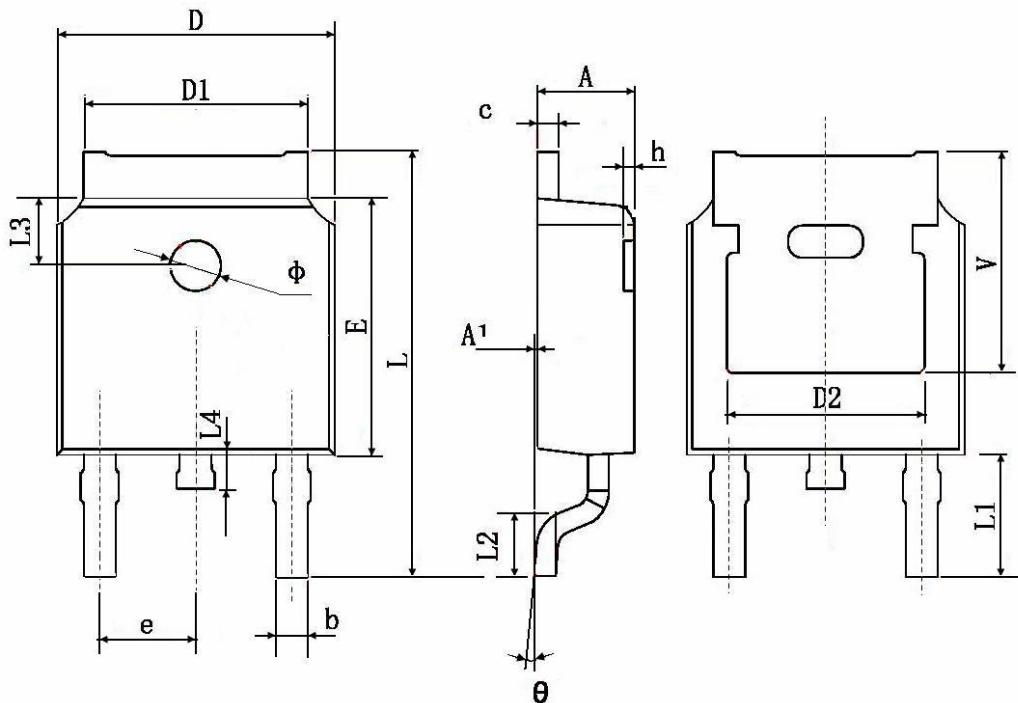


Figure.13 Typical Gate Charge vs Gate to Source Voltage



TO-252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	0.483 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211 TYP.	



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